



**THE DATASHEET OF  
2PD2150,115**



## Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of <http://www.nxp.com>, <http://www.philips.com/> or <http://www.semiconductors.philips.com/>, use <http://www.nexperia.com>

Instead of [sales.addresses@www.nxp.com](mailto:sales.addresses@www.nxp.com) or [sales.addresses@www.semiconductors.philips.com](mailto:sales.addresses@www.semiconductors.philips.com), use [salesaddresses@nexperia.com](mailto:salesaddresses@nexperia.com) (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

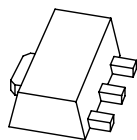
Should be replaced with:

- © **Nexperia B.V. (year). All rights reserved.**

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via [salesaddresses@nexperia.com](mailto:salesaddresses@nexperia.com)). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia



# 2PD2150

20 V, 3 A NPN low  $V_{CEsat}$  (BISS) transistor

Rev. 02 — 2 January 2007

Product data sheet

## 1. Product profile

### 1.1 General description

NPN low  $V_{CEsat}$  Breakthrough In Small Signal (BISS) transistor in a medium power SOT89 (SC-62/TO-243) flat lead Surface-Mounted Device (SMD) plastic package.

PNP complement: 2PB1424.

### 1.2 Features

- Low collector-emitter saturation voltage  $V_{CEsat}$
- High collector current capability  $I_C$  and  $I_{CM}$
- High collector current gain ( $h_{FE}$ ) at high  $I_C$
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

### 1.3 Applications

- DC-to-DC conversion
- MOSFET gate driving
- Motor control
- Charging circuits
- Power switches (e.g. motors, fans)
- Thin Film Transistor (TFT) backlight inverter

### 1.4 Quick reference data

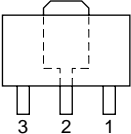
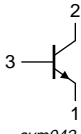
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	20	V
$I_C$	collector current		-	-	3	A
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	-	5	A
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 2$ A; $I_B = 0.1$ A	[1]	0.2	0.5	V

[1] Pulse test:  $t_p \leq 300$   $\mu$ s;  $\delta \leq 0.02$ .

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	emitter		 sym042
2	collector		
3	base		

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
2PD2150	SC-62	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89

## 4. Marking

Table 4. Marking codes

Type number	Marking code
2PD2150	M2

## 5. Limiting values

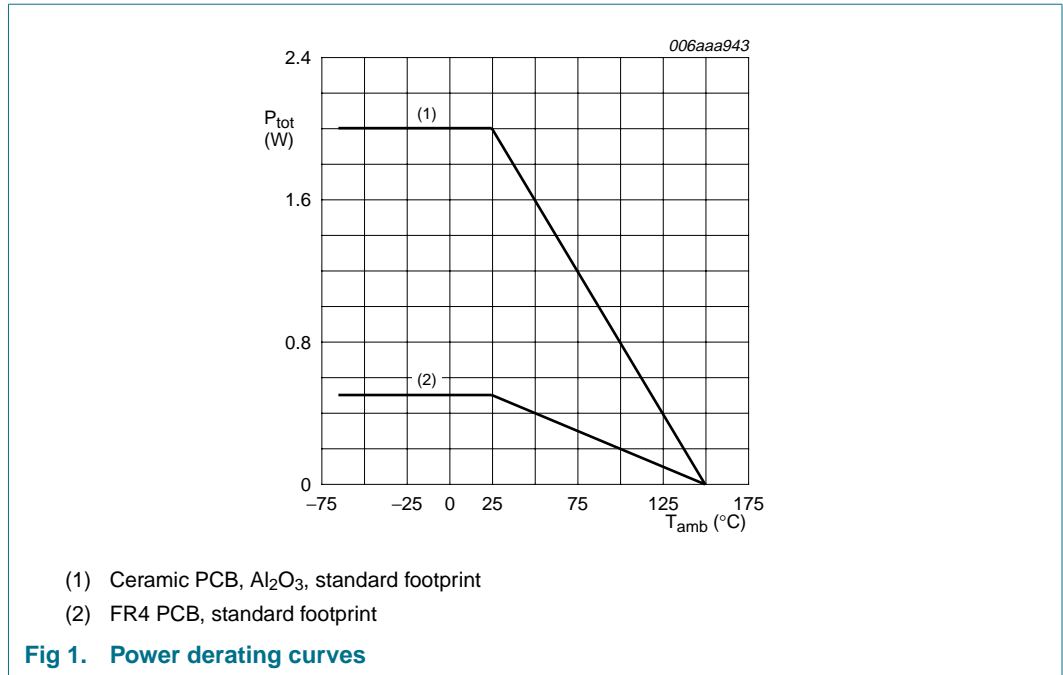
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	40	V
$V_{CEO}$	collector-emitter voltage	open base	-	20	V
$V_{EBO}$	emitter-base voltage	open collector	-	6	V
$I_C$	collector current		-	3	A
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms	-	5	A
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	0.5	W
			[2]	2	W
$T_j$	junction temperature		-	150	°C
$T_{amb}$	ambient temperature		-65	+150	°C
$T_{stg}$	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on a ceramic PCB,  $Al_2O_3$ , standard footprint.



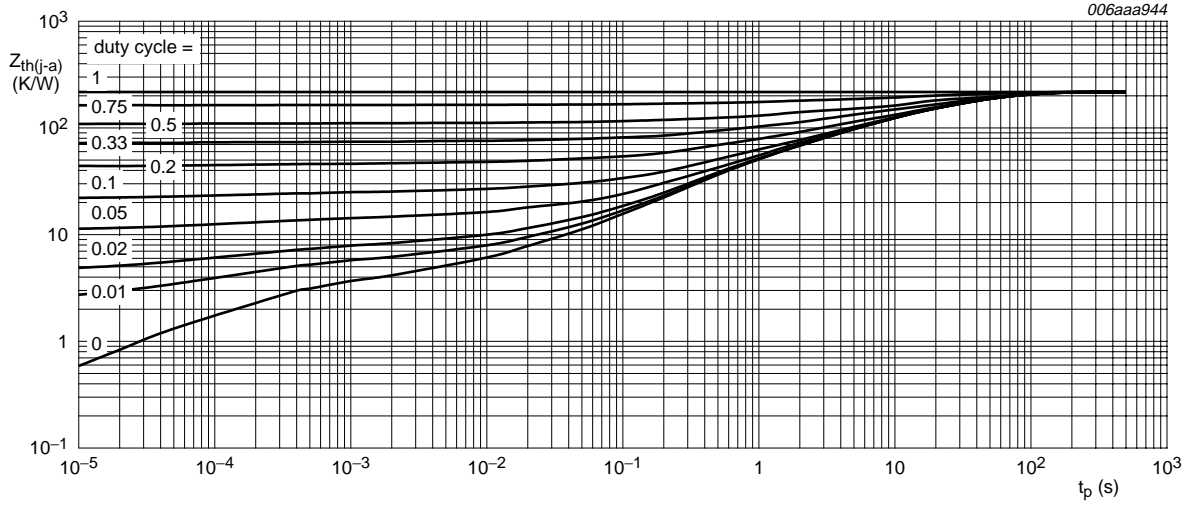
## 6. Thermal characteristics

**Table 6. Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	250	K/W
			[2]	-	62	K/W

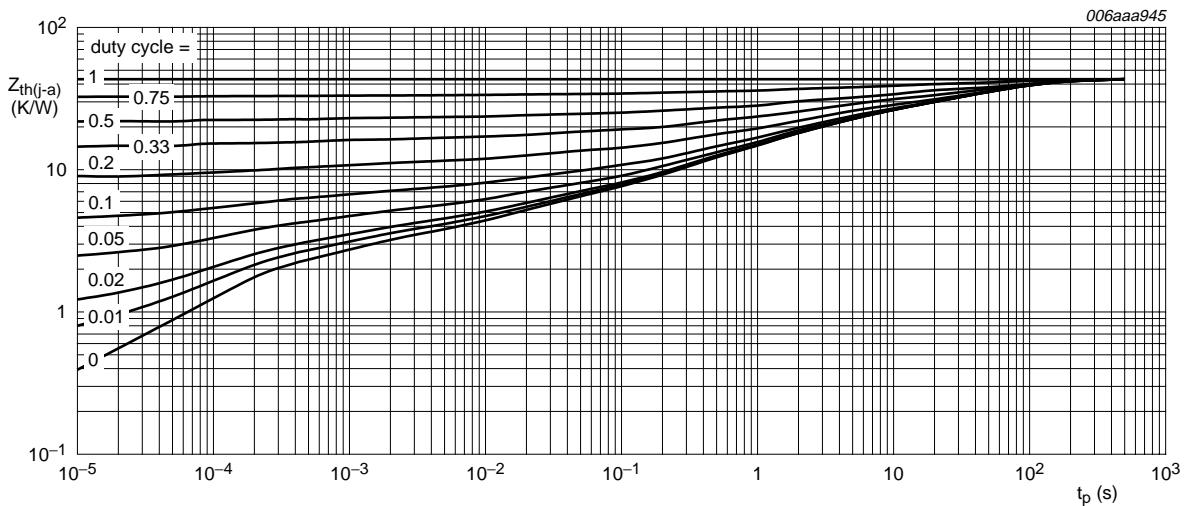
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



FR4 PCB, standard footprint

Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB,  $Al_2O_3$ , standard footprint

Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

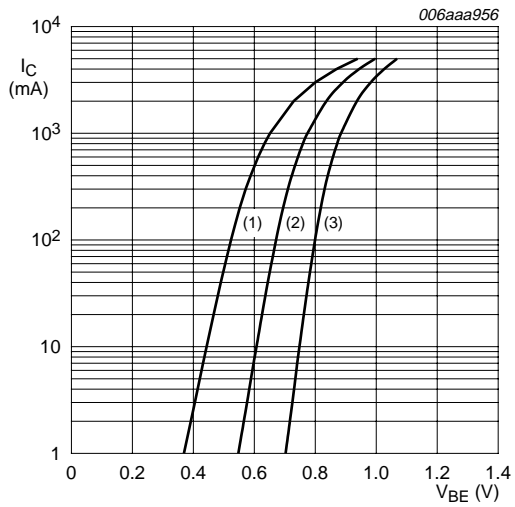
## 7. Characteristics

**Table 7. Characteristics**

$T_{amb} = 25^\circ\text{C}$  unless otherwise specified.

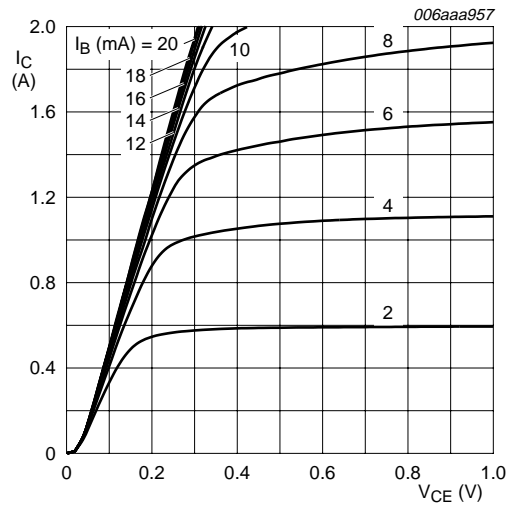
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 30\text{ V}; I_E = 0\text{ A}$	-	-	0.1	$\mu\text{A}$
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}$	-	-	0.1	$\mu\text{A}$
$h_{FE}$	DC current gain	$V_{CE} = 2\text{ V}; I_C = 0.1\text{ A}$	180	-	390	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 2\text{ A}; I_B = 0.1\text{ A}$	[1]	0.2	0.5	V
$f_T$	transition frequency	$V_{CE} = 2\text{ V}; I_E = -0.5\text{ A};$ $f = 100\text{ MHz}$	-	220	-	MHz
$C_{ib}$	common-base input capacitance	$V_{EB} = 5\text{ V}; I_E = i_e = 0\text{ A};$ $f = 1\text{ MHz}$	-	180	-	pF
$C_{ob}$	common-base output capacitance	$V_{CB} = 10\text{ V}; I_E = i_e = 0\text{ A};$ $f = 1\text{ MHz}$	-	20	-	pF

[1] Pulse test:  $t_p \leq 300\ \mu\text{s}; \delta \leq 0.02$ .



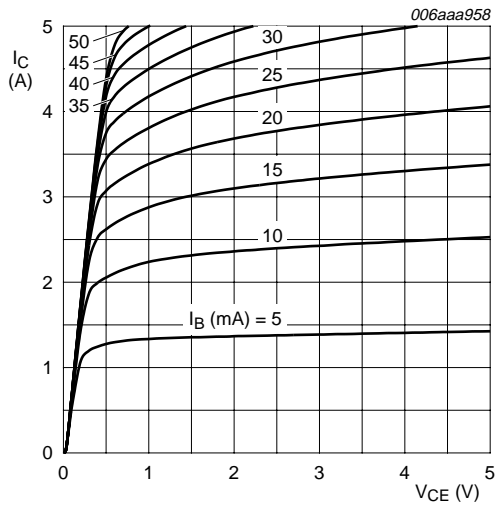
$V_{CE} = 2\text{ V}$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

**Fig 4. Collector current as a function of base-emitter voltage; typical values**



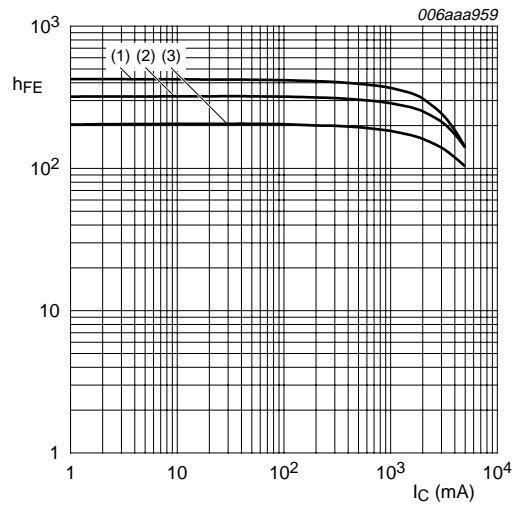
$T_{amb} = 25\text{ °C}$

**Fig 5. Collector current as a function of collector-emitter voltage; typical values**



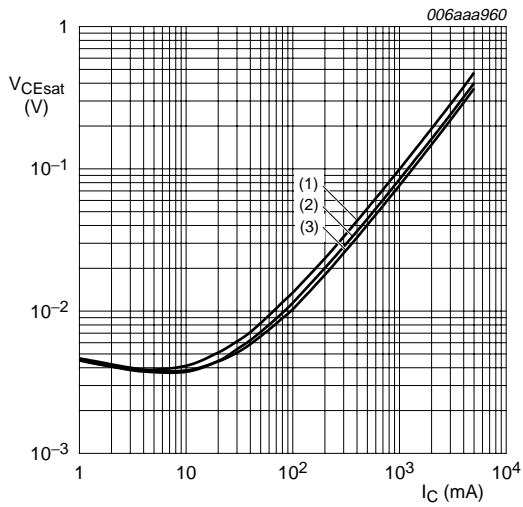
$T_{amb} = 25\text{ °C}$

**Fig 6. Collector current as a function of collector-emitter voltage; typical values**



$V_{CE} = 2\text{ V}$   
 (1)  $T_{amb} = 100\text{ °C}$   
 (2)  $T_{amb} = 25\text{ °C}$   
 (3)  $T_{amb} = -40\text{ °C}$

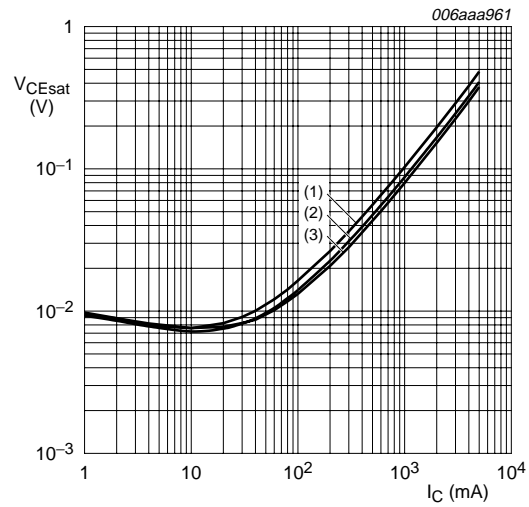
**Fig 7. DC current gain as a function of collector current; typical values**



$I_C/I_B = 10$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -40\text{ °C}$

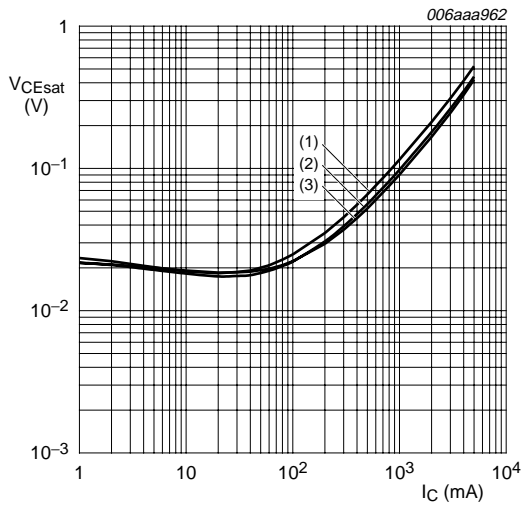
**Fig 8. Collector-emitter saturation voltage as a function of collector current; typical values**



$I_C/I_B = 20$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -40\text{ °C}$

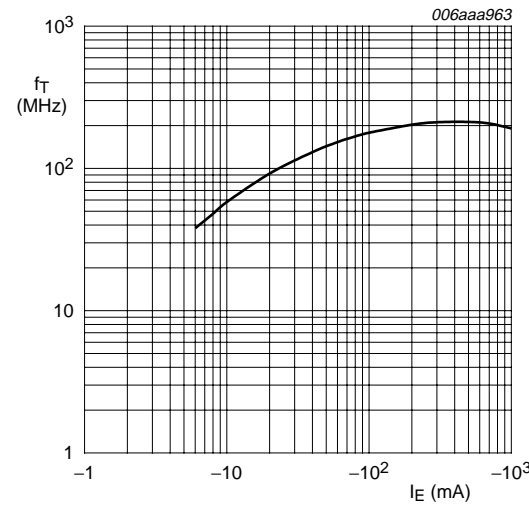
**Fig 9. Collector-emitter saturation voltage as a function of collector current; typical values**



$I_C/I_B = 50$

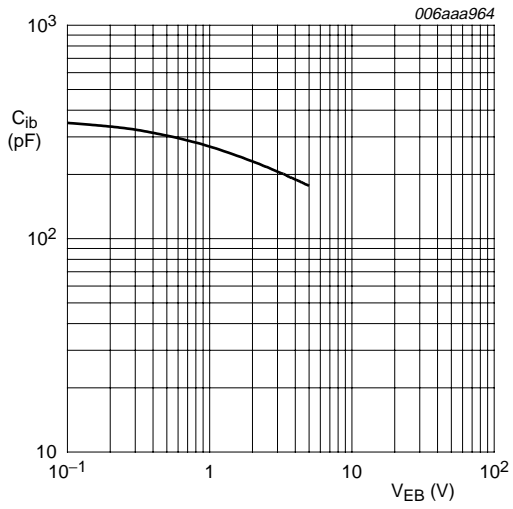
- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -40\text{ °C}$

**Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values**



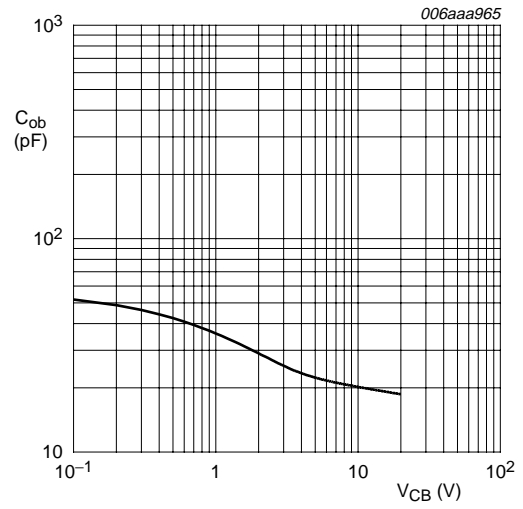
$T_{amb} = 25\text{ °C}; V_{CE} = 2\text{ V}$

**Fig 11. Transition frequency as a function of emitter current; typical values**



$T_{amb} = 25\text{ }^\circ\text{C}; f = 1\text{ MHz}; I_E = i_e = 0\text{ A}$

**Fig 12. Common-base input capacitance as a function of emitter-base voltage; typical values**



$T_{amb} = 25\text{ }^\circ\text{C}; f = 1\text{ MHz}; I_E = i_e = 0\text{ A}$

**Fig 13. Common-base output capacitance as a function of collector-base voltage; typical values**

## 8. Package outline

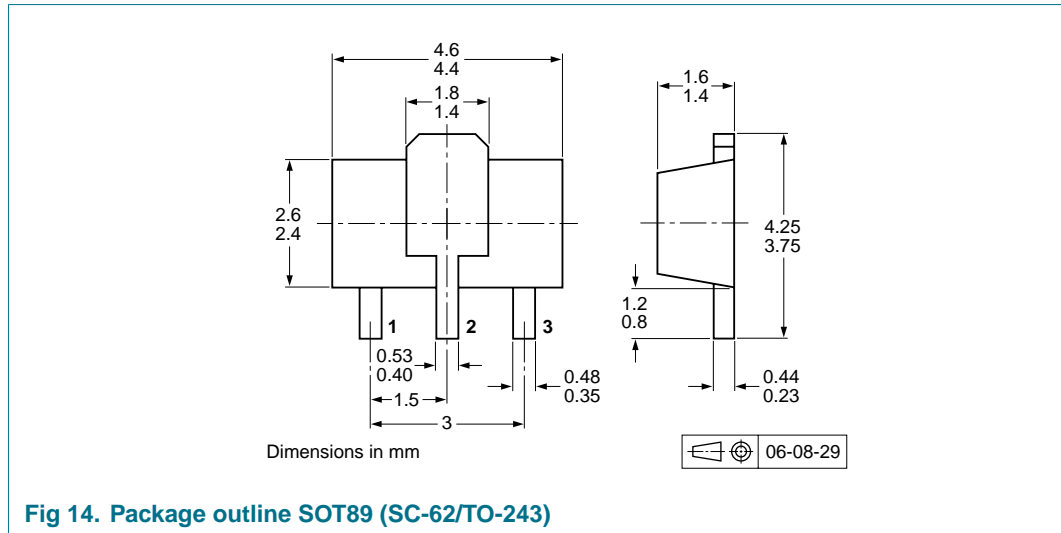


Fig 14. Package outline SOT89 (SC-62/TO-243)

## 9. Packing information

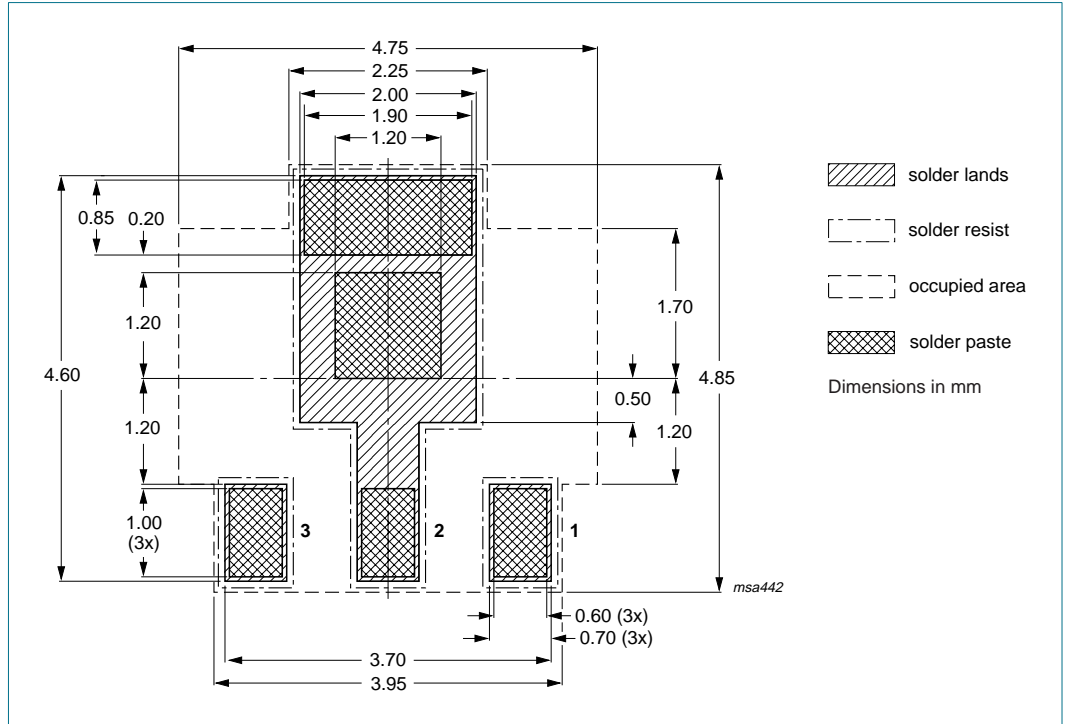
**Table 8. Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.<sup>[1]</sup>

Type number	Package	Description	Packing quantity	
			1000	4000
2PD2150	SOT89	8 mm pitch, 12 mm tape and reel	-115	-135

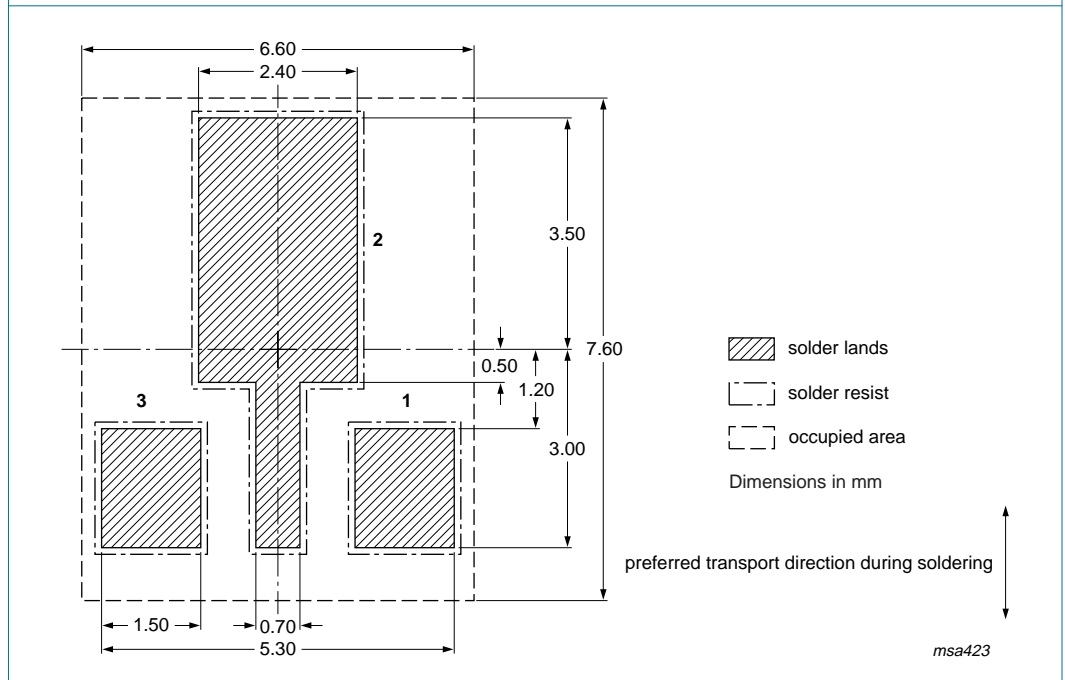
[1] For further information and the availability of packing methods, see [Section 13](#).

10. Soldering



SOT89 standard mounting conditions for reflow soldering

Fig 15. Reflow soldering footprint SOT89 (SC-62/TO-243)



Not recommended for wave soldering

Fig 16. Wave soldering footprint SOT89 (SC-62/TO-243)

## 11. Revision history

**Table 9. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
2PD2150_2	20070102	Product data sheet	-	2PD2150_1
Modifications:	<ul style="list-style-type: none"> <li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>• Legal texts have been adapted to the new company name where appropriate.</li> <li>• <a href="#">Table 1 “Quick reference data”</a>: <math>I_C</math> collector current added</li> <li>• <a href="#">Table 1 “Quick reference data”</a>: <math>I_{CM}</math> peak collector current maximum value adapted</li> <li>• <a href="#">Table 1 “Quick reference data”</a>: <math>V_{CEsat}</math> collector-emitter saturation voltage added</li> <li>• <a href="#">Table 5 “Limiting values”</a>: <math>V_{CEO}</math> collector-emitter voltage maximum value adapted</li> <li>• <a href="#">Table 5 “Limiting values”</a>: <math>I_C</math> collector current maximum value adapted</li> <li>• <a href="#">Table 5 “Limiting values”</a>: <math>I_{CM}</math> peak collector current maximum value adapted</li> <li>• <a href="#">Table 5 “Limiting values”</a>: <math>P_{tot}</math> total power dissipation for ceramic PCB condition added</li> <li>• <a href="#">Figure 1 “Power derating curves”</a>: adapted</li> <li>• <a href="#">Table 6 “Thermal characteristics”</a>: adapted</li> <li>• <a href="#">Table 6 “Thermal characteristics”</a>: <math>R_{th(j-a)}</math> thermal resistance from junction to ambient for ceramic PCB condition added</li> <li>• <a href="#">Figure 2</a>: <math>t_p</math> pulse time redefined to pulse duration</li> <li>• <a href="#">Figure 3</a>: added</li> <li>• <a href="#">Table 7 “Characteristics”</a>: <math>V_{CEsat}</math> collector-emitter saturation voltage typical value added</li> <li>• <a href="#">Table 7 “Characteristics”</a>: <math>f_T</math> transition frequency conditions slightly changed</li> <li>• <a href="#">Table 7 “Characteristics”</a>: <math>C_{ib}</math> common-base input capacitance added</li> <li>• <a href="#">Table 7 “Characteristics”</a>: <math>C_{ob}</math> common-base output capacitance added</li> <li>• <a href="#">Figure 4</a>, <a href="#">6</a>, <a href="#">10</a>, <a href="#">11</a>, <a href="#">12</a>, <a href="#">13</a> and <a href="#">16</a>: added</li> <li>• <a href="#">Figure 5</a>, <a href="#">7</a>, <a href="#">8</a> and <a href="#">9</a>: adapted</li> <li>• <a href="#">Section 12 “Legal information”</a>: updated</li> </ul>			
2PD2150_1	20050422	Product data sheet	-	-

## 12. Legal information

### 12.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 12.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

### 12.3 Disclaimers

**General** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

**Terms and conditions of sale** — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

### 12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 13. Contact information

For additional information, please visit: <http://www.nxp.com>

For sales office addresses, send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

## 14. Contents

<b>1</b>	<b>Product profile</b> . . . . .	<b>1</b>
1.1	General description . . . . .	1
1.2	Features . . . . .	1
1.3	Applications . . . . .	1
1.4	Quick reference data . . . . .	1
<b>2</b>	<b>Pinning information</b> . . . . .	<b>2</b>
<b>3</b>	<b>Ordering information</b> . . . . .	<b>2</b>
<b>4</b>	<b>Marking</b> . . . . .	<b>2</b>
<b>5</b>	<b>Limiting values</b> . . . . .	<b>2</b>
<b>6</b>	<b>Thermal characteristics</b> . . . . .	<b>3</b>
<b>7</b>	<b>Characteristics</b> . . . . .	<b>5</b>
<b>8</b>	<b>Package outline</b> . . . . .	<b>9</b>
<b>9</b>	<b>Packing information</b> . . . . .	<b>9</b>
<b>10</b>	<b>Soldering</b> . . . . .	<b>10</b>
<b>11</b>	<b>Revision history</b> . . . . .	<b>11</b>
<b>12</b>	<b>Legal information</b> . . . . .	<b>12</b>
12.1	Data sheet status . . . . .	12
12.2	Definitions . . . . .	12
12.3	Disclaimers . . . . .	12
12.4	Trademarks . . . . .	12
<b>13</b>	<b>Contact information</b> . . . . .	<b>12</b>
<b>14</b>	<b>Contents</b> . . . . .	<b>13</b>

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.



© NXP B.V. 2007. **All rights reserved.**  
 For more information, please visit: <http://www.nxp.com>  
 For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)  
 Date of release: 2 January 2007  
 Document identifier: 2PD2150\_2

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- [View 2PD2150,115 on WIN SOURCE](#)
- [Nexperia USA Inc. Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

- ✓ Global Sourcing Solution
- ✓ Obsolete Management
- ✓ Cost Control Management
- ✓ Shortage Management
- ✓ Alternative Solution
- ✓ Excess Inventory Management